NSN 5962-01-116-5781

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5962-01-116-5781

Body Length:

Between 0.755 inches and 0.790 inches

Body Width:

Between 0.265 inches and 0.300 inches

Body Height:

Between 0.155 inches and 0.175 inches

Maximum Power Dissipation Rating:

307.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

6930-01-102-2345 36378

Features Provided:

Hermetically sealed and monolithic and positive outputs and w/enable and programmable

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Chacteristic:

40.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level

output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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